

Medium Power Phase Control Thyristors (Stud Version), 25 A



TO-48 (TO-208AA)

FEATURES

- Improved glass passivation for high reliability and exceptional stability at high temperature
- High di/dt and dV/dt capabilities
- Standard package
- Low thermal resistance
- Metric threads version available
- Types up to 1200 V V_{DRM}/V_{RRM}
- Designed and qualified for industrial and consumer level
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
COMPLIANT

PRIMARY CHARACTERISTICS

$I_{T(AV)}$	25 A
V_{DRM}/V_{RRM}	100 V, 200 V, 400 V, 600 V, 800 V, 1000 V 1200 V
V_{TM}	1.70 V
I_{GT}	60 mA
T_J	-65 °C to +125 °C
Package	TO-48 (TO-208AA)
Circuit configuration	Single SCR

TYPICAL APPLICATIONS

- Medium power switching
- Phase control applications

MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{T(AV)}$		25	A
	T_C	85	°C
$I_{T(RMS)}$		40	A
I_{TSM}	50 Hz	420	A
	60 Hz	440	
I^2t	50 Hz	867	A ² s
	60 Hz	790	
V_{DRM}/V_{RRM}		100 to 1200	V
t_q	Typical	110	μs
T_J		-65 to +125	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{DRM}/V_{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE ⁽¹⁾ V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE ⁽²⁾ V	I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA
VS-25RIA	10	100	150	20
	20	200	300	10
	40	400	500	
	60	600	700	
	80	800	900	
	100	1000	1100	
	120	1200	1300	

Notes

⁽¹⁾ Units may be broken over non-repetitively in the off-state direction without damage, if di/dt does not exceed 20 A/μs

⁽²⁾ For voltage pulses with $t_p \leq 5$ ms

**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average on-state current at case temperature	$I_{T(AV)}$	180° sinusoidal conduction		25	A
				85	°C
Maximum RMS on-state current	$I_{T(RMS)}$			40	A
Maximum peak, one-cycle non-repetitive surge current	I_{TSM}	t = 10 ms	No voltage reapplied	420	A
		t = 8.3 ms	No voltage reapplied	440	
		t = 10 ms	100 % V_{RRM} reapplied	350	
		t = 8.3 ms	100 % V_{RRM} reapplied	370	
Maximum I^2t for fusing	I^2t	t = 10 ms	No voltage reapplied	867	A^2s
		t = 8.3 ms	No voltage reapplied	790	
		t = 10 ms	100 % V_{RRM} reapplied	615	
		t = 8.3 ms	100 % V_{RRM} reapplied	560	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 to 10 ms, no voltage reapplied, $T_J = T_J$ maximum		8670	$A^2\sqrt{s}$
Low level value of threshold voltage	$V_{T(TO)1}$	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ maximum		0.99	V
High level value of threshold voltage	$V_{T(TO)2}$	$(I > \pi \times I_{T(AV)})$, $T_J = T_J$ maximum		1.40	
Low level value of on-state slope resistance	r_{t1}	$(16.7\% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$, $T_J = T_J$ maximum		10.1	mΩ
High level value of on-state slope resistance	r_{t2}	$(I > \pi \times I_{T(AV)})$, $T_J = T_J$ maximum		5.7	
Maximum on-state voltage	V_{TM}	$I_{pk} = 79$ A, $T_J = 25$ °C		1.70	V
Maximum holding current	I_H	$T_J = 25$ °C, anode supply 6 V, resistive load		130	mA
Latching current	I_L			200	

SWITCHING

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum rate of rise of turned-on current	dI/dt	$T_J = T_J$ maximum, $V_{DM} = \text{Rated } V_{DRM}$ Gate pulse = 20 V, 15 Ω, $t_p = 6$ μs, $t_r = 0.1$ μs maximum $I_{TM} = (2 \times \text{rated dI/dt})$ A	200	A/μs
			180	
			160	
			150	
Typical turn-on time	t_{gt}	$T_J = 25$ °C, at rated V_{DRM}/V_{RRM} , $T_J = 125$ °C	0.9	μs
Typical reverse recovery time	t_{rr}	$T_J = T_J$ maximum, $I_{TM} = I_{T(AV)}$, $t_p > 200$ μs, dI/dt = - 10 A/μs	4	
Typical turn-off time	t_q	$T_J = T_J$ maximum, $I_{TM} = I_{T(AV)}$, $t_p > 200$ μs, $V_R = 100$ V, dI/dt = - 10 A/μs, dV/dt = 20 V/μs linear to 67 % V_{DRM} , gate bias 0 V to 100 W	110	

BLOCKING

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 100 % rated V_{DRM}	100	V/μs
		$T_J = T_J$ maximum linear to 67 % rated V_{DRM}	300 ⁽¹⁾	

Note

⁽¹⁾ Available with: dV/dt = 1000 V/μs, to complete code add S90 i.e. 25RIA120S90



TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum peak gate power	P _{GM}	T _J = T _J maximum		8.0	W
Maximum average gate power	P _{G(AV)}			2.0	
Maximum peak positive gate current	I _{GM}	T _J = T _J maximum		1.5	A
Maximum peak negative gate voltage	-V _{GM}	T _J = T _J maximum		10	V
DC gate current required to trigger	I _{GT}	T _J = - 65 °C	Maximum required gate trigger current/voltage are the lowest value which will trigger all units 6 V anode to cathode applied	90	mA
		T _J = 25 °C		60	
		T _J = 125 °C		35	
DC gate voltage required to trigger	V _{GT}	T _J = - 65 °C		3.0	V
		T _J = 25 °C		2.0	
		T _J = 125 °C		1.0	
DC gate current not to trigger	I _{GD}	T _J = T _J maximum, V _{DRM} = Rated value		2.0	mA
DC gate voltage not to trigger	V _{GD}	T _J = T _J maximum, V _{DRM} = Rated value	Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.2	V

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum operating junction and storage temperature range	T _J , T _{Stg}		-65 to +125	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.75	K/W
Maximum thermal resistance, case to heat sink	R _{thCS}	Mounting surface, smooth, flat and greased	0.35	
Allowable mounting torque		Non-lubricated threads	3.4 + 0 - 10 % (30)	N · m (lbf · in)
		Lubricated threads	2.3 + 0 - 10 % (20)	
Approximate weight			14	g
			0.49	oz.
Case style		See dimensions - link at the end of datasheet	TO-48 (TO-208AA)	

ΔR_{thJC} CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.17	0.13	$T_J = T_J$ maximum	K/W
120°	0.21	0.22		
90°	0.27	0.30		
60°	0.40	0.42		
30°	0.69	0.70		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

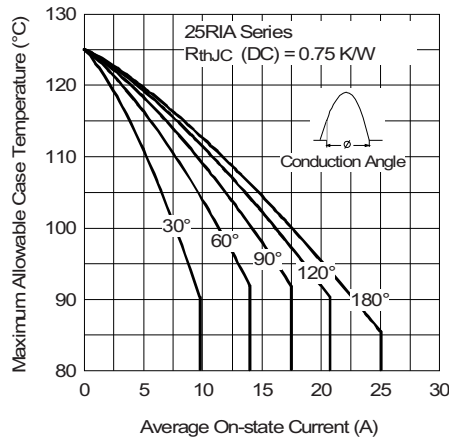


Fig. 1 - Current Ratings Characteristics

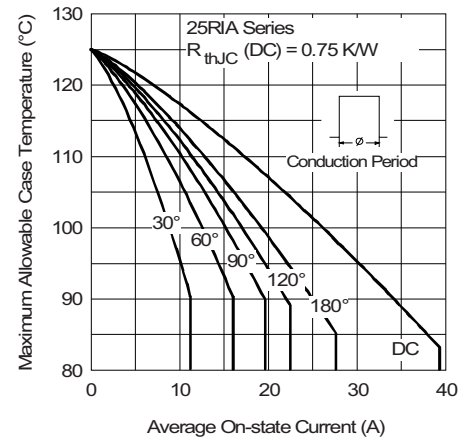


Fig. 1 - Current Ratings Characteristics

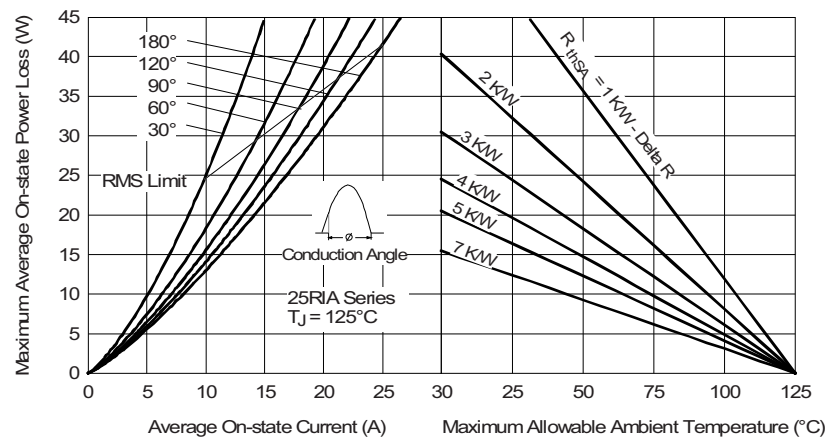


Fig. 2 - On-State Power Loss Characteristics

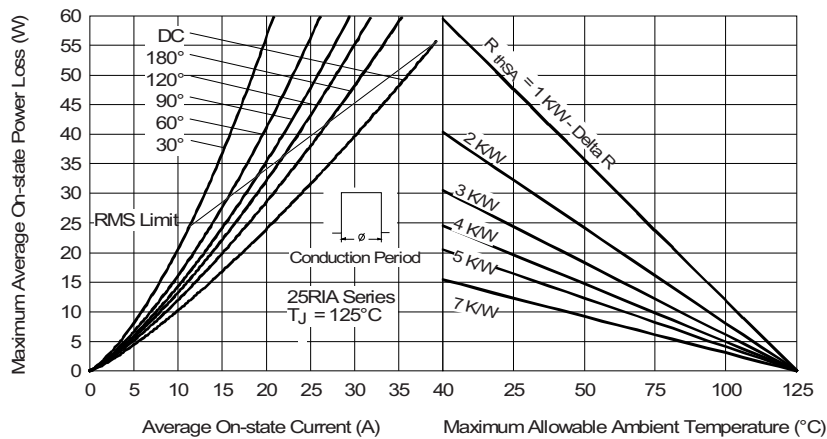


Fig. 3 - On-State Power Loss Characteristics

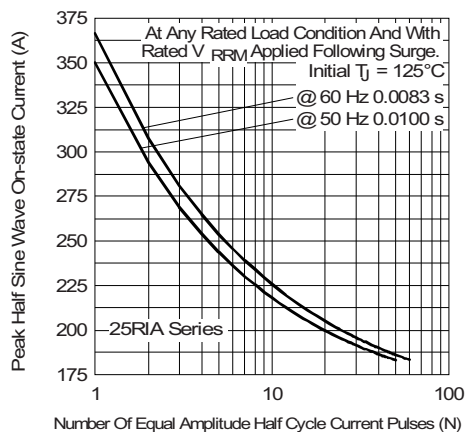


Fig. 4 - Maximum Non-Repetitive Surge Current

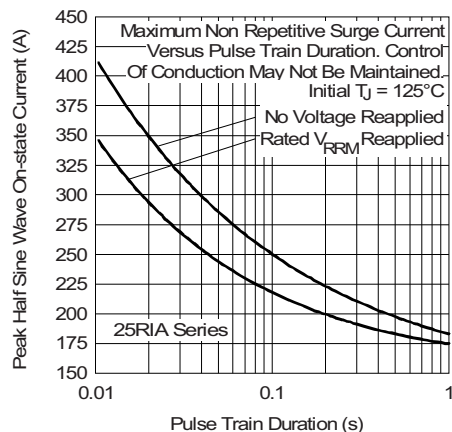


Fig. 5 - Maximum Non-Repetitive Surge Current

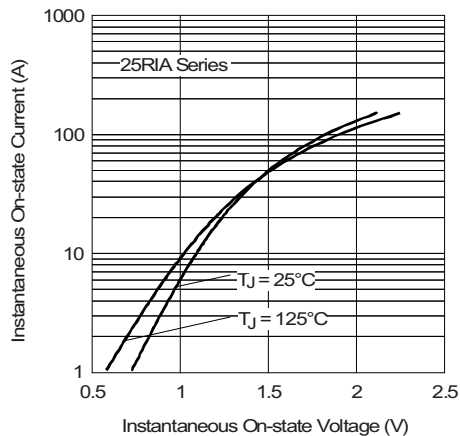


Fig. 6 - Forward Voltage Drop Characteristics

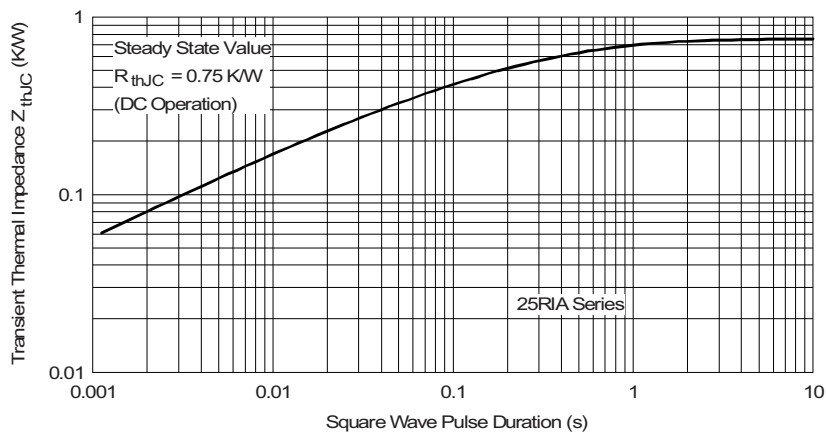


Fig. 7 - Thermal Impedance Z_{thJC} Characteristics

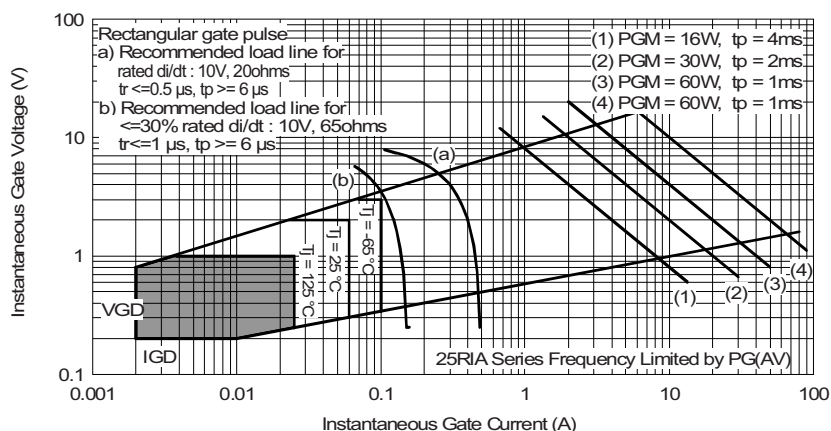


Fig. 8 - Gate Characteristics

ORDERING INFORMATION TABLE

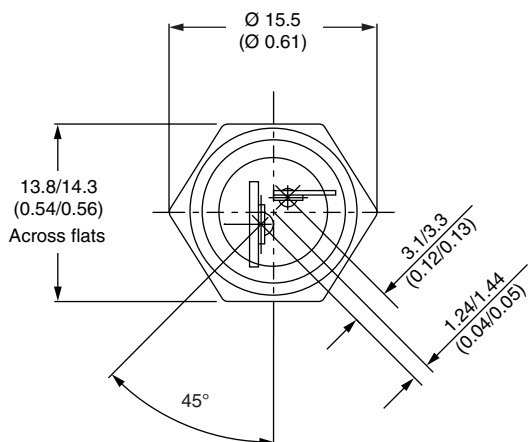
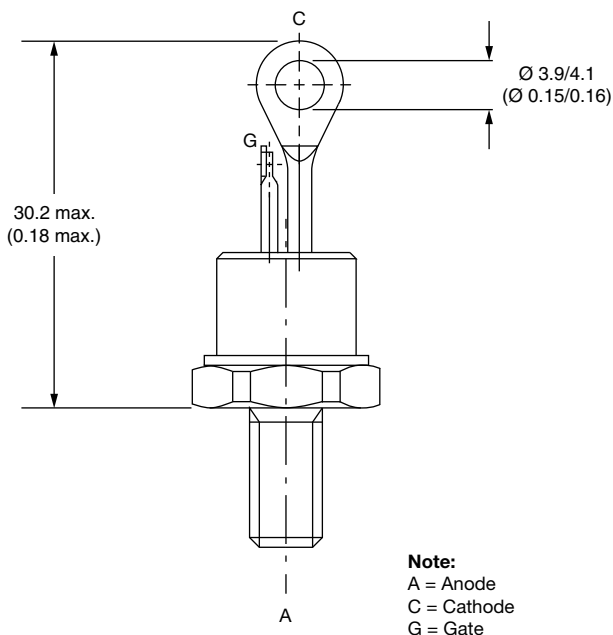
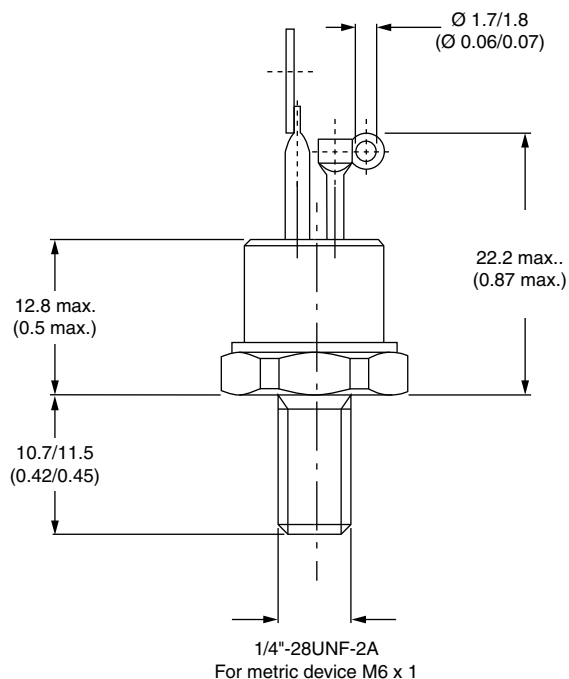
Device code	VS-	25	RIA	120	M	S90
	1	2	3	4	5	6
1	Vishay Semiconductors product					
2	Current code					
3	Essential part number					
4	Voltage code x 10 = V_{RRM} (see Voltage Ratings table)					
5	None = stud base TO-48 (TO-208AA) 1/4" 28UNF-2A M = stud base TO-48 (TO-208AA) M6 x 1					
6	Critical dV/dt : None = 300 V/ μs (standard value) S90 = 1000 V/ μs (special selection)					

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95333



TO-208AA (TO-48)

DIMENSIONS in millimeters (inches)





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